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### **SL2364**

#### **VERY HIGH PERFORMANCE TRANSISTOR ARRAYS**

The SL2364 is an array of transistors internally connected to form a dual long-tailed pair with tail transistors. This is a monolithic integrated circuit manufactured on a very high speed bipolar process which has a minimum useable  $f_T$  of 2.5GHz, (typically 5GHz).

The SL2364 is in a 14 SO package and a high performance Dilmon encapsulation.

#### **FEATURES**

- Complete Dual Long-Tailed Pair in One Package
- Very High f<sub>T</sub> Typically 5 GHz
- Very Good Matching Including Thermal Matching

#### **APPLICATIONS**

- Wide Band Amplification Stages
- 140 and 560 MBit PCM Systems
- Fibre Optic Systems
- High Performance Instrumentation
- Radio and Satellite Communications

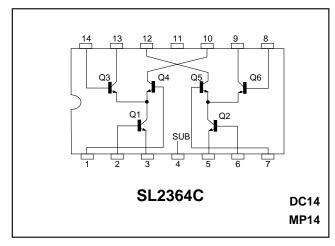


Fig. 1 Pin connections (top view)

#### **ELECTRICAL CHARACTERISTICS**

These characteristics are guaranteed of the following conditions (unless otherwise stated):  $T_{amb} = 22^{\circ}C \pm 2^{\circ}C$ 

Characteristics   Min.   Typ.	Max.	Units	Conditions
1			
$ \begin{array}{ c c c c c c } & LV_{\text{CEO}} & & 6 & 9 \\ BV_{\text{EBO}} & & 2.5 & 5.0 \\ BV_{\text{CIO}} & & 16 & 40 \\ h_{\text{FE}} & & 50 & 80 \\ f_{\text{T}} & & 2.5 & 5 \\ \Delta V_{\text{BE}} (\text{See note 1}) & & 2 \\ \Delta V_{\text{BE}} / T_{\text{AMB}} & & -1.7 \\ C_{\text{CB}} & & 0.5 \\ C_{\text{CI}} & & 1.0 \\ \end{array} $	5 0.8 1.5	V V V GHz mV mV/°C pF	$\begin{split} I_{c} &= 10 \mu A \\ I_{c} &= 5 m A \\ I_{E} &= 10 \mu A \\ I_{C} &= 10 \mu A \\ I_{C} &= 8 m A, \ V_{CE} = 2 V \\ I_{C} \ Tail) &= 8 m A, \ V_{CE} = 2 V \\ I_{C} \ Tail) &= 8 m A, \ V_{CE} = 2 V \\ I_{C} \ Tail) &= 8 m A, \ V_{CE} = 2 V \\ V_{CB} &= 0 \\ V_{CI} &= 0 \end{split}$

NOTE 1.  $\Delta V_{BE}$  applies to  $|V_{BEQ3} - V_{BEQ4}|$  and  $|V_{BEQ5} - V_{BEQ6}|$ 

#### **TYPICAL CHARACTERISTICS**

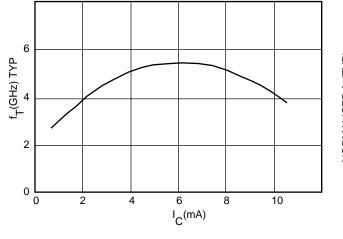


Fig. 2 Collector current

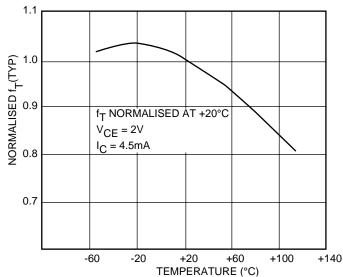


Fig. 3 Chip temperature

#### **ABSOLUTE MAXIMUM RATINGS**

Maximum individual transistor dissipation 200mW

Storage temperature -55°C to + 150°C Maximum junction temperature + 150°C

Package thermal resistance (°C/W):

**Chip to case** 45 (MP14) 35 (DC14) **Chip to ambient** 123 (MP14) 120 (DC14)

VCBO = 10V, VEBO = 2 5V VCEO = 6V. VCIO = 15V IC (any one transistor) = 20mA

The substrate should be connected to the most negative point of the circuit to maintain electrical isolation between the transistors.



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